TOSHIBA Field Effect Transistor Silicon N Channel Dual Gate MOS Type

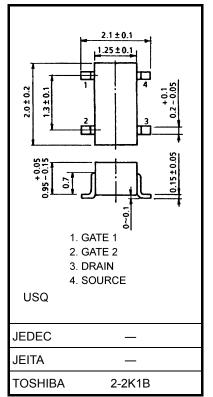
3SK256

TV Tuner, UHF RF Amplifier Applications

- Superior cross modulation performance.
- Low reverse transfer capacitance: $C_{rss} = 0.015 \text{ pF}$ (typ.)
- Low noise figure: NF = 1.9dB (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	13.5	V
Gate 1-source voltage	V _{G1S}	±8	V
Gate 2-source voltage	V _{G2S}	±8	V
Drain current	I _D	30	mA
Drain power dissipation	PD	100	mW
Channel temperature	T _{ch}	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.006 g (typ.)

absolute maximum ratings. Please design the appropriate reliability upon reviewing the

operating temperature/current/voltage, etc.) are within the

Note: Using continuously under heavy loads (e.g. the application of high

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

temperature/current/voltage and the significant change in

Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

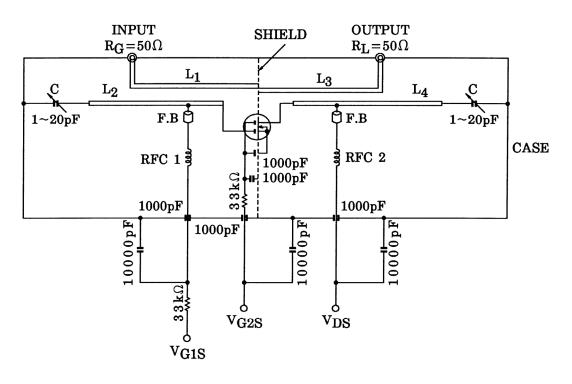
Symbol Characteristics **Test Condition** Min Typ. Max Unit Gate 1 leakage current $V_{DS} = 0, V_{G1S} = \pm 6 V, V_{G2S} = 0$ ±50 nA IG1SS Gate 2 leakage current $V_{DS} = 0, V_{G1S} = 0, V_{G2S} = \pm 6 V$ ±50 I_{G2SS} nA V_{G1S} = -1 V, V_{G2S} = -1 V Drain-source voltage V (BR) DSX 13.5 V $I_D = 100 \ \mu A$ Drain current IDSS $V_{DS} = 6 V, V_{G1S} = 0, V_{G2S} = 4.5 V$ 0 0.1 mΑ ____ $V_{DS} = 6 V, V_{G2S} = 4.5 V, I_D = 100 \mu A$ 0 1.0 V Gate 1-source cut-off voltage VG1S (OFF) $V_{DS} = 6 V, V_{G1S} = 4 V, I_D = 100 \mu A$ 0.5 1.5 V Gate 2-source cut-off voltage V_{G2S} (OFF) 10 V_{DS} = 6 V, V_{G2S} = 4.5 V Forward transfer admittance |Y_{fs}| 21.5 ____ mS $I_D = 10 \text{ mA}, f = 1 \text{ kHz}$ Input capacitance Ciss V_{DS} = 6 V, V_{G2S} = 4.5 V 1.0 1.6 2.4 pF pF Reverse transfer capacitance $I_D = 10 \text{ mA}, \text{ f} = 1 \text{ MHz}$ 0.015 0.03 Crss ____ G_{ps} V_{DS} = 6 V, V_{G2S} = 4.5 V 18 19.5 dB Power gain ____ I_D = 10 mA, f = 800 MHz NF 1.9 Noise figure 3.0 dB

Electrical Characteristics (Ta = 25°C)

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Unit: mm



L₁~L₄: ϕ 0.8 mm silver plated copper wire

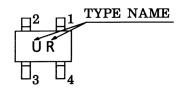
C: Air trimmer TTA25A200A (MURATA Manufacturing, Co., Ltd.)

RFC 1: $\phi0.35$ mm copper wire 3 mm ID, 7 T

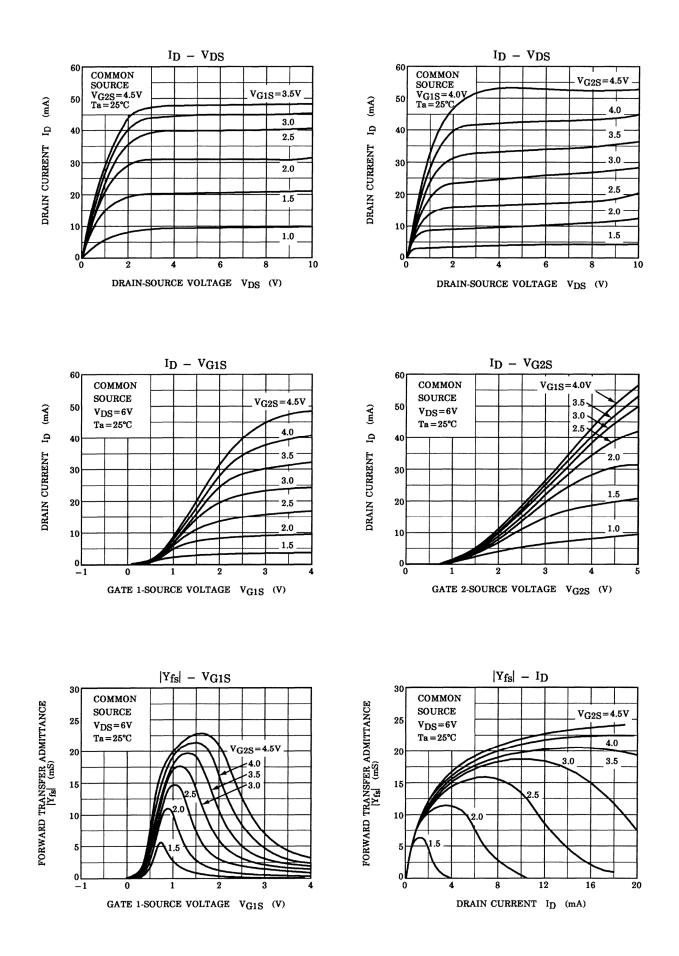
RFC 2: $\phi 0.35~mm$ copper wire 3 mm ID, 10 T



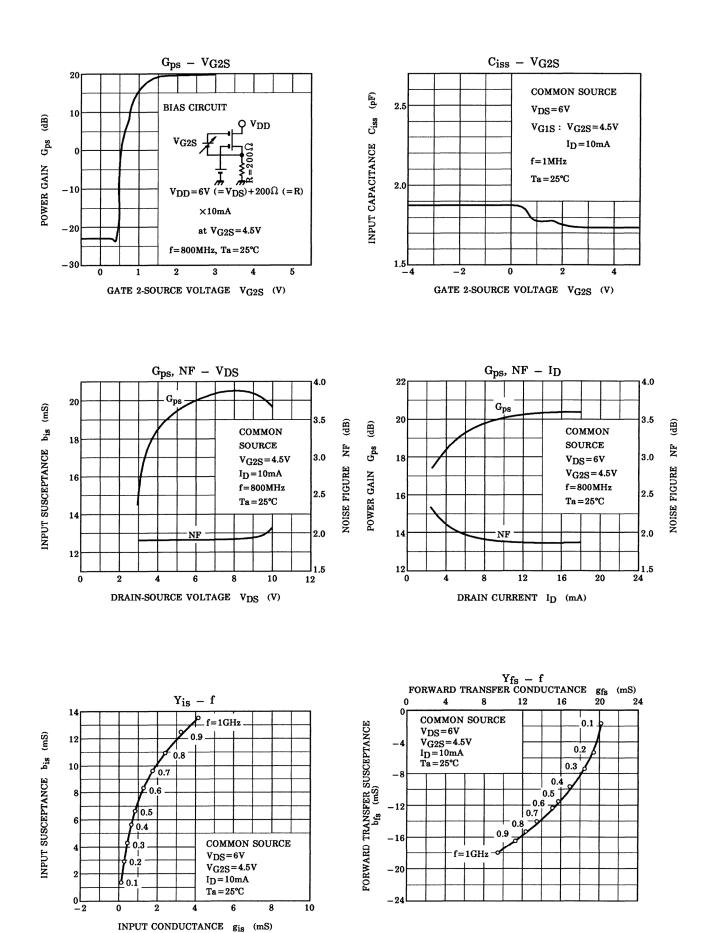
Marking



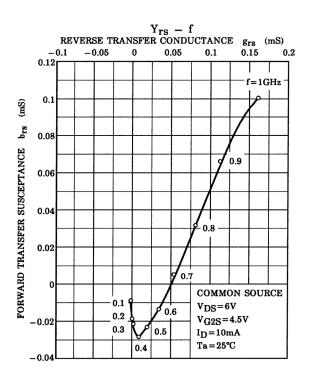
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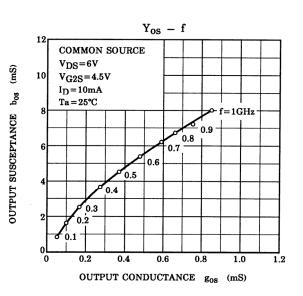


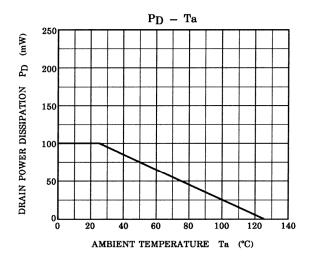
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20070701-EN GENERAL

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